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PRODUCT CHANGE NOTICE

PCN Form (D4-E000-73)

PCN #17-005

NOTIFICATION DATE: February 15, 2017

MODEL(S) AFFECTED:

M3SWA-2-50DR+, SWMA-2-50DR+, YSWA-2-50DR+ (and YSWA-2-50DR) M3SW-2-50DR+, SWM-2-50DR+, YSW-2-50DR+ (and YSW-2-50DR)

EXTENT OF CHANGE:

- Discontinuation of model series and replacement by M3SWA-2-50DRA+ (see spec sheet below on pg.3)
- See Replacement Guide and Web Datasheet for performance and specifications
- Reflective models to use Absorptive version **NOTE:** Replacement part requires use of external blocking capacitors
- Discontinuation of Non-RoHS version of YSW/YSWA

EFFECT OF CHANGE:

- No Change to FIT for the M3SWA/M3SW models
- Change of FIT and FORM for SWMA/SWM/YSWA/YSW
- Change to FORM (marking) and FUNCTION (see datasheet)

REASON FOR CHANGE:

- Discontinuation of original die.
- Alternate qualified die requires customer circuit to include blocking capacitors.
- Discontinuation of non-RoHS YSW/YSWA for industry demand

EFFECTIVE DATE OF CHANGE:

Change to take place beginning in Jan 2017 based on stock and availability of previous finish. LAST TIME BUY to be offered based on availability.

ATTACHMENTS:

Datasheet for M3SWA-2-50DRA+

QUESTIONS? PLEASE CONTACT US.

AS 9100 ISO 9001 ISO 14001 Certified



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Attachment to PCN#17-005

** List of Affected Models **			
Existing P/N:	Existing P/N: Replacement P/N:		
M3SW-2-50DR+		<u>AN-80-012</u>	
M3SWA-2-50DR+	M3SWA-2-50DRA+	<u>AN-80-013</u>	
SWM-2-50DR+		AN-80-014	
SWMA-2-50DR+		<u>AN-80-015</u>	
YSW-2-50DR+		<u>AN-80-016</u>	
YSWA-2-50DR+		<u>AN-80-017</u>	

50Ω 0.3 - 4500 MHz

Absorptive RF Switch with internal driver Single Supply Voltage, +3V to +5V

Product Features

- High Isolation, 52 dB at 1 GHz
- Low insertion loss, 0.8 dB typ. at 1 GHz
- Low supply current consumption, 50 μA typ.
- Fast Rise/Fall time, 16 ns typ.



CASE STYLE: DL805

+RoHS Compliant
The +Suffix identifies RoHS Compliance. See our web site for RoHS Compliance methodologies and qualifications

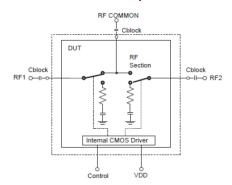
Typical Applications

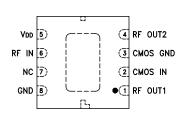
- Defense
- Communication Infrastructure
- Test and Measurements

General Description

M3SWA-2-50DRA+ is a high isolation fast switching absorptive SPDT switch with integral CMOS driver, operates with single positive supply voltage while consuming, $50 \mu A$ typical. It has been designed for wideband operation. It is packaged in a tiny 3.25mm x 3.25mm, 8-lead package passes 250V for ESD (HBM).

Simplified Schematic and Pad Description





Function	Pad Number	Description
RF IN	6	RF common/ SUM port, requires external DC block
RF OUT1	1	RF out #1/In port #1, requires external DC block
RF OUT2	4	RF out #1/In port #2, requires external DC block
CONTROL	2	CMOS Control IN
VDD	5	Supply voltage
NC	7	No Connection
CMOS GND	3	CMOS ground
GND	8 &, paddle	RF ground



RF Electrical Specifications¹, T_{AMB} =25°C, 50 Ω , V_{DD} = +5V

Parameter	Condition (MHz)	Min.	Тур.	Max.	Units
Frequency range		10		4500	MHz
	10		0.6	1.0	
	100		0.7	1.0	
Insertion loss ^{2,3}	1000		0.8	1.2	dB
	2000		1.0	1.4	
	4500		1.2	1.9	
	10		74.0		
	100		59.3		
Isolation between Common port and RF1/RF2 Ports	1000		61.5		dB
	2000		50.8		
	4500		39.5		
	10		74.3		
	100		61.0		
Isolation between RF1 and RF2 ports	1000		51.8		dB
	2000		46.5		
	4500		37.4		
	10		24.3		
	100		24.1		
Return loss (ON STATE)	1000		20.8		dB
	2000		16.7		
	4500		17.0		
Return loss (OFF STATE)	500		12.9		
	1000		20.1		
	2000		28.6		dB
	4500		12.8		
Input 0.2 dB Compression	500-1000		30		
	1000-2000		30		dBm
	2000-4500		27		

DC Electrical Specifications

Parameter	Min.	Тур.	Max.	Units
Supply voltage, V _{DD}	3.0		5.0	V
Supply current		50	200	μA
Control voltage Low	0		0.5	V
Control voltage High	0.7 V _{DD}		V_{DD}	V
Control current		0.2	10	μΑ

- Notes:

 1. Tested on Mini-Circuits' test board TB-159+, using Agilent's N5230A network analyzer (see Characterization test circuit, Fig.1).

 2. Insertion loss values are de-embedded from test board loss.

 3. Needs external blocking capacitors on all RF ports. (Suggested value=47pF)

Switching Specifications

Parameter	Condition	Min.	Тур.	Max.	Units
Switching time 50% Control to 90%/10% RF	RF Pin=0dBm RF Freq.=500 MHz Control Freq.=500 KHz Control High=3.7V Control Low=0V		29		nS
Video Leakage	RF Pin=0dBm RF Freq.=500 MHz Control Freq.=500 KHz Control High=3.7V Control Low=0V		24.8		mV
Rise/Fall Time 10 to 90% or 90 to 10%	RF Pin=0dBm RF Freq.=500 MHz Control Freq.=500 KHz Control High=3.7V Control Low=0V		16		nS

Absolute Maximum Ratings⁵

Parameter	Ratings
Operating temperature	-55°C to +100°C
Storage temperature	-55°C to +100°C
V _{DD} , Supply voltage (V)	2.7 Min., 5.5 Max.
Voltage control (V)	-0.2V Min., V _{DD} Max
RF Input power (dBm)	+30 dBm

^{5.} Operation of this device above any of these conditions may cause permanent damage.

Truth Table (State of control voltage selects the desired switch state)

State of Control voltage	RF common to		
State of Control Voltage	RF1	RF2	
Hi	OFF	ON	
Low	ON	OFF	

ON- low insertion loss state OFF- Isolation State

Characterization Test Circuit

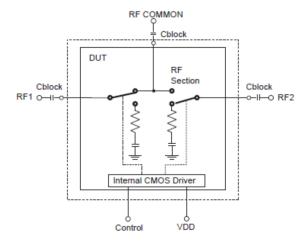
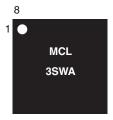


Figure 1. Block Diagram of test Circuit used for characterization (DUT soldered on Mini-Circuit's TB-159A+)

Frequency	Cblock	
(MHz)	(Suggested Value)	
0.3-500	0.1 μF	
500-4500	47 pF	

Product Marking



Marking may contain other features or characters for internal lot control

Additional Detailed Technical Information

additional information is available on our dash board.

Performance Data	Data Table	
Performance Data	Swept Graphs	
Case Style	DL805 Plastic package, exposed paddle	
Tape & Reel	F58	
Standard quantities available on reel	7" reels with 1000 devices 13" reels with 2000, 4000 devices	
Suggested Layout for PCB Design	PL-120A	
Evaluation Board	TB-159A+	
Environmental Ratings	ENV16	

ESD Rating

Human Body Model (HBM): Class 1A (250 to 500V) in accordance with ESD STM5.1-2001

Additional Notes

- A. Performance and quality attributes and conditions not expressly stated in this specification document are intended to be excluded and do not form a part of this specification document.
- B. Electrical specifications and performance data contained in this specification document are based on Mini-Circuit's applicable established test performance criteria and measurement instructions.
- C. The parts covered by this specification document are subject to Mini-Circuits standard limited warranty and terms and conditions (collectively, "Standard Terms"); Purchasers of this part are entitled to the rights and benefits contained therein. For a full statement of the Standard Terms and the exclusive rights and remedies thereunder, please visit Mini-Circuits' website at www.minicircuits.com/MCLStore/terms.jsp

